

# **UHF** variable capacitance diode

## **FEATURES**

- · Excellent linearity
- Excellent matching to 2% DMA
- · Ultra small plastic SMD package
- · C28: 2.1 pF; ratio: 9
- · Low series resistance.

#### **APPLICATIONS**

- · Electronic tuning in UHF television tuners
- · Voltage controlled oscillators

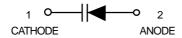
#### **DESCRIPTION**

The BB179B is a planar technology variable capacitance diode, in a SOD523 (SC-79) package. The excellent matching performance is achieved by gliding matching and a direct matching assembly procedure.



**BB 179B** 





LIMITING VALUES In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>R</sub>	continuous reverse voltage		_	32	V
V <sub>RM</sub>	peak reverse voltage	in series with a 10 $k\Omega$ resistor	-	35	V
I <sub>F</sub>	continuous forward current		-	20	mΑ
T stg	storage temperature		-55	+150	°C
T <sub>j</sub>	operating junction temperature		-55	+125	°C

## **ELECTRICAL CHARACTERISTICS** T<sub>j</sub>=25°C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	TYP.	UNIT
I <sub>R</sub>	reverse current	$V_R = 30 V$ ; see Fig.2	_	_	10	nΑ
		$V_R = 30 \text{ V}; T_j = 85^{\circ}\text{C}; \text{ see Fig.2}$	_	_	200	nΑ
r s	diode series resistance	f = 470 MHz;	_	0.6	0.75	Ω
		$V_R$ is the value at which Cd = 9 pF				
C d	diode capacitance	$V_R = 1 V$ ; $f = 1 MHz$ ; see Figs 1and 3	18.22	-	20	pF
		$V_R = 28 V$ ; f = 1 MHz; see Figs 1and 3	1.9	_	2.25	pF
$\frac{C_{d(1V)}}{C_{d(2V)}}$	capacitance ratio	f = 1 MHz	-	1.27	-	
C <sub>d(1V)</sub>	capacitance ratio	f = 1 MHz	8.45	-	10	
C <sub>d(25V)</sub>	capacitance ratio	f = 1 MHz	-	1.05	-	
C <sub>d</sub>	capacitance matching	V <sub>R</sub> =1 to 28 V; in a sequence of 15 diodes(gliding)	_	<del>-</del>	2	%



### **BB 179B**

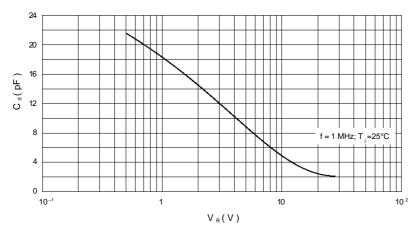


Fig.1 Diode capacitance as a function of reverse voltage; typical values.

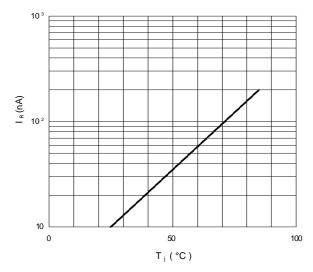


Fig.2 Reverse current as a function of junction temperature; maximum values.

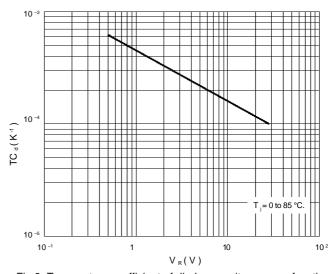


Fig.3 Temperature coefficient of diode capacitance as a function of reverse voltage; typical values.